

μClamp1211Z Ultra Small μClamp® 1 Line, 12V ESD Protection

PROTECTION PRODUCTS

Description

μClamp® TVS diodes are designed to protect sensitive electronics from damage or latch-up due to ESD. They features large cross-sectional area junctions for conducting high transient currents. These devices offer desirable characteristics for board level protection including fast response time, low operating and clamping voltage, and no device degradation.

The μ Clamp®1211Z is in a 2-pin SLP0603P2X3 package. It measures 0.6 x 0.3 mm with a nominal height of only 0.25mm. The leads are finished with lead-free NiAu. Each device will protect one line operating at 12 volts. It gives the designer the flexibility to protect single lines in applications where arrays are not practical. The combination of small size and high ESD surge capability makes them ideal for use in portable applications such as cellular phones, digital cameras, and tablet PC's.

Features

- High ESD withstand Voltage: +/-30kV (Contact/Air) per IEC 61000-4-2
- Able to withstand over 1000 ESD strikes per IEC61000-4-2 Level 4
- Ultra-small 0201 package
- Protects one data line or power line
- Low leakage current: <50nA (V_□=12V)
- Working voltage: +/-12V
- Low dynamic resistance: 0.30 Ω (typ)
- Solid-state silicon-avalanche technology

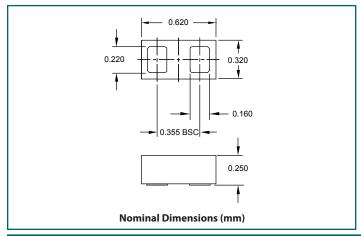
Mechanical Characteristics

- SLP0603P2X3 package
- Pb-Free, Halogen Free, RoHS/WEEE compliant
- Nominal Dimensions: 0.6 x 0.3 x 0.25 mm
- Lead Finish: NiAu
- Marking: Marking code + dot matrix date code
- · Packaging: Tape and Reel

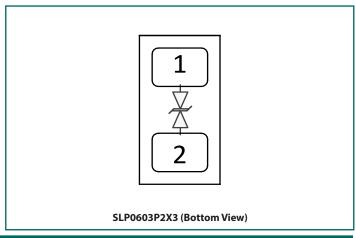
Applications

- Cellular Handsets & Accessories
- Portable Instrumentation
- 12V Power Protection
- Tablet PC

Package Dimension



Schematic & Pin Configuration



Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power (tp = 8/20μs)	P _{PK}	175	W
Peak Pulse Current (tp = 8/20μs)	I _{PP}	7	Α
ESD per IEC 61000-4-2 (Air) ⁽¹⁾ ESD per IEC 61000-4-2 (Contact) ⁽¹⁾	V _{ESD}	±30 ±30	kV
Operating Temperature	T _J	-55 to +125	∘C
Storage Temperature	T _{STG}	-55 to +150	°C

Electrical Characteristics (T=25°C unless otherwise specified)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Units
Reverse Stand-Off Voltage	V _{RWM}	Pin1 to 2 or 2 to 1				12	٧
Reverse Breakdown Voltage	V _{BR}	I _t = 1mA, Pin 1 to 2 or 2 to 1		14.2	15.8	18	V
Reverse Leakage Current	I _R	V _{RWM} = 12V, Pin 1 to 2 or 2 to 1			<5	50	nA
Clamping Voltage	V _C	I _{pp} =1A, tp = 8/20μs, Pin1 to 2 or 2 to 1				20	V
Clamping Voltage	V _C	I _{pp} =7A, tp=8/20μs Pin1 to 2 or 2 to 1				25	V
ECD CL : V II 2	.,		$I_{pp} = 4A$		17.2		.,
ESD Clamping Voltage ²	V_{c} $t_{p} = 0.2/100 \text{ns}$	I _{pp} = 16A		21		V	
Dynamic Resistance ^{2,3}	R _{DYN}	$t_p = 0.2/100$ ns			0.30		Ω
Junction Capacitance	C _J	$V_R = 0V, f = 1MHz$	T = 25°C		19	25	pF

Notes

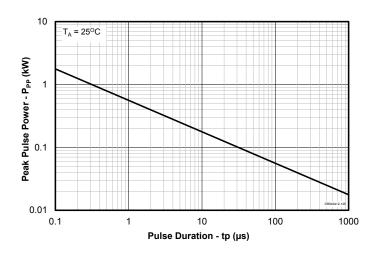
¹⁾ ESD gun return path connected to ESD ground plane.

²⁾ Transmission Line Pulse Test (TLP) Settings: tp = 100ns, tr = 0.2ns, I_{TLP} and V_{TLP} averaging window: t1 = 70ns to t2 = 90ns.

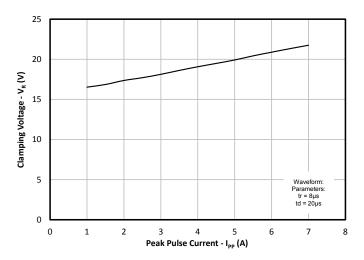
³⁾ Dynamic resistance calculated from $\rm I_{\rm TLP} = 4A$ to $\rm I_{\rm TLP} = 16A$

Typical Characteristics

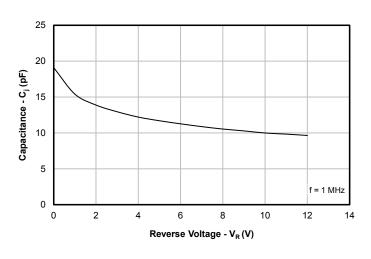
Non-Repetitive Peak Pulse Power vs. Pulse Time



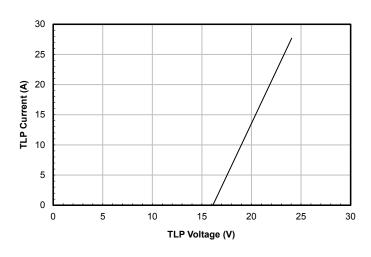
Clamping Voltage vs. Peak Pulse Current (tp=8/20 µs)



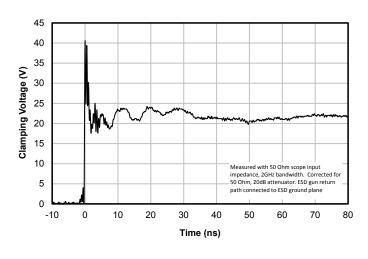
Capacitance vs. Reverse Voltage



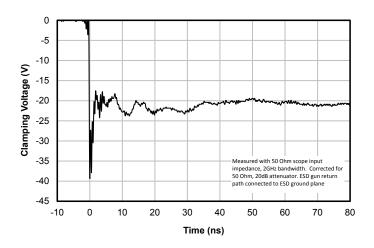
TLP Characteristic (Positive Pulse)



ESD Clamping (8kV Contact per IEC 61000-4-2)



ESD Clamping (-8kV Contact per IEC 61000-4-2)



Rev 5.1

2/22/2017

Application Information

Assembly Guidelines

The small size of this device means that some care must be taken during the mounting process to insure reliable solder joints. The figure at the right details Semtech's recommended mounting pattern. Recommended assembly guidelines are shown in Table 1. Note that these are only recommendations and should serve only as a starting point for design since there are many factors that affect the assembly process. Exact manufacturing parameters will require some experimentation to get the desired solder application.

Solder Stencil

Stencil design is one of the key factors which will determine the volume of solder paste which is deposited onto the land pad. The area ratio of the stencil aperture will determine how well the stencil will print. The area ratio takes into account the aperture shape, aperture size, and stencil thickness. A minimum area ratio of 0.66 is preferred for the subject package. The area ratio of a rectangular aperture is given as:

Area Ratio = (L * W) / (2 * (L + W) * T)

Where:

L = Aperture Length

W = Aperture Width

T = Stencil Thickness

Semtech recommends a stencil with square aperture and rounded corners for consistent solder release. The stencil should be laser cut with electropolished finish. A stencil thickness of 0.075mm (0.003") is recommended. A 0.100mm (0.004") stencil may be used, however the stencil opening may need to be increased slightly to achieve the desired area ratio to ensure proper solder coverage on the pad.

Recommended Mounting Pattern

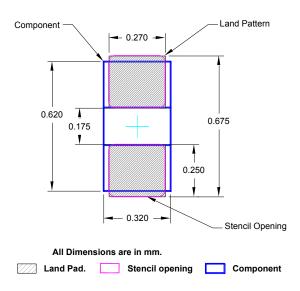
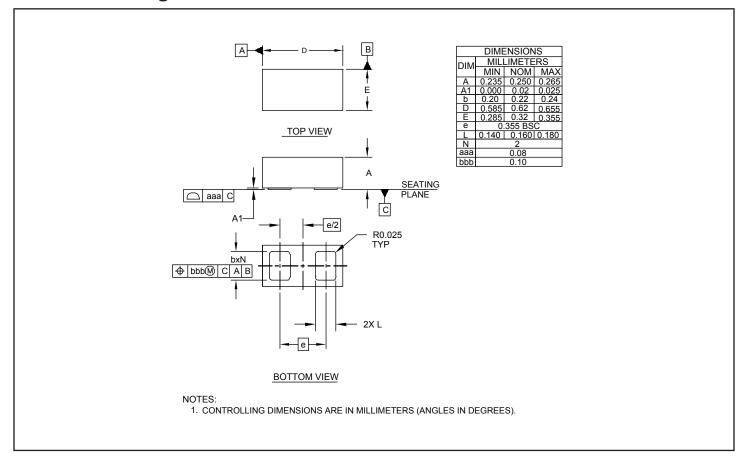


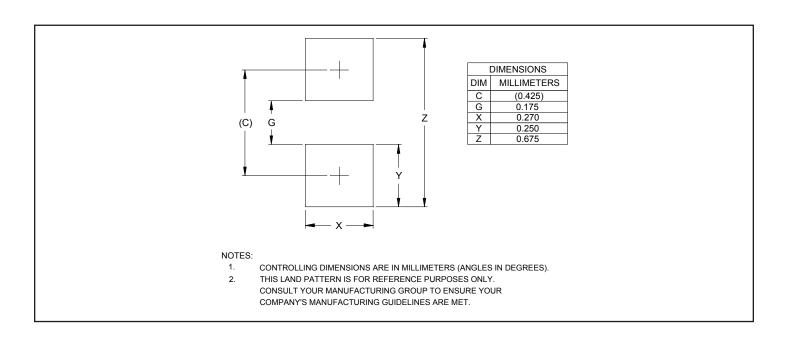
Table 1 - Assembly Guidelines

Assembly Parameter	Recommendation		
Solder Stencil Design	Laser Cut, Electro-Polishe		
Aperture Shape	Rectangular with Rounded Corners		
Solder Stencil Thickness	0.075mm (0.003") or 0.100mm (0.004")		
Solder Paste Type	Type 4 Size Sphere or Smaller		
Solder Reflow Profile	Per JEDEC J-STD-020		
PCB Solder Pad Design	Solder Mask Defined		
PCB Pad Finish	OSP or NiAu		

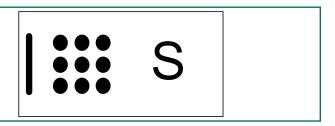
Outline Drawing - SLP0603P2X3



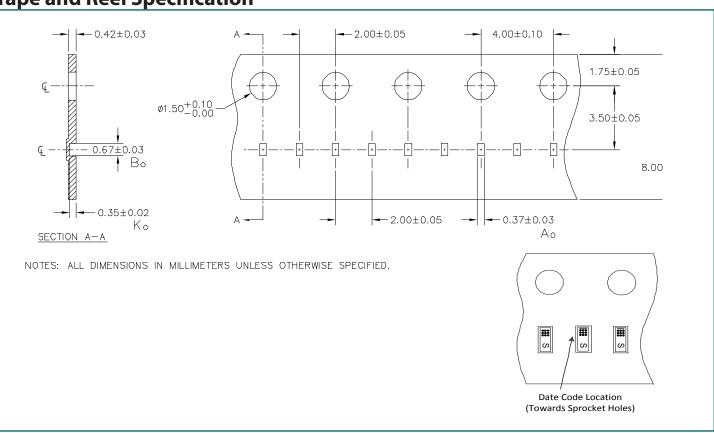
Land Pattern - SLP0603P2X3



Marking Code



Tape and Reel Specification



Ordering Information

Part Number	Qty per Reel	Reel Size
μClamp1211Z.TFT	15,000	7"